

**XiPos**™  
Extra Power Solution

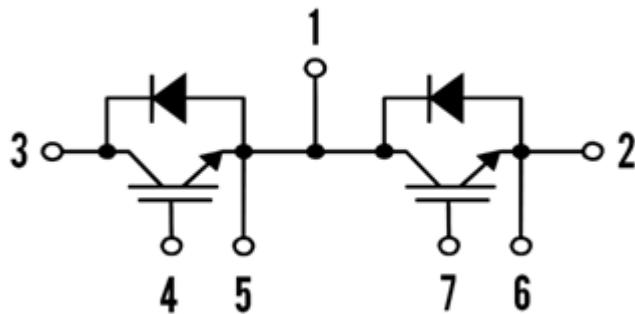


**600V  
200A**

PACKAGE : M1

**PRELIMINARY**

■ CIRCUIT DIAGRAM



■ FEATURES

- IGBT3 Trench Technology
- 6us short circuit capability at  $T_{vj} = 150^\circ\text{C}$
- Positive  $V_{CE(on)}$  temperature coefficient
- Industry standard package

■ APPLICATIONS

- High power inverter
- Switched mode power supplies (SMPS)
- UPS
- Electrical welding machine

■ ABSOLUTE MAXIMUM RATINGS

$T_c=25^\circ\text{C}$ , unless otherwise specified

Symbol	Parameter	Conditions	Ratings	Unit
$V_{CES}$	Collector-emitter voltage	-	600	V
$I_c$	DC-collector current	$T_c = 25^\circ\text{C}$	260	A
		$T_c = 80^\circ\text{C}$	200	A
$I_{CRM}$	Repetitive peak collector current	1ms	400	A
$V_{GES}$	Gate-emitter peak voltage	-	$\pm 20$	V
$I_F$	Diode continuous forward current	-	200	A
$I_{FRM}$	Diode repetitive peak forward current	-	400	A
$T_{vj,max}$	Maximum junction temperature	-	-40 ~ 175	$^\circ\text{C}$
$T_{vj,op}$	Operating temperature range	-	-40 ~ 150	$^\circ\text{C}$
$T_{stg}$	Storage temperature range	-	-40 ~ 125	$^\circ\text{C}$
$V_{ISOL}$	Insulation test voltage	50/60Hz, $t=1\text{min}$ $I_{ISOL}=1\text{mA}$	2.5	kV
$M_S$	Mounting screw torque	M6	3.0 ~ 6.0	N.m
$M_t$	Mounting terminals screw torque	M5	2.5 ~ 5.0	N.m

Technical information and specification subject to change without notice.

## PRELIMINARY

## ■ ELECTRICAL CHARACTERISTICS OF IGBT

 $T_j=25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Min	Typ	Max	Unit	Conditions
$V_{CE(\text{Sat})}$	C-E saturation voltage	-	1.45	-	V	$I_C = 200\text{A}$ , $V_{GE} = 15\text{V}$ , $T_{vj} = 25^\circ\text{C}$
		-	1.70	-	V	$I_C = 200\text{A}$ , $V_{GE} = 15\text{V}$ , $T_{vj} = 150^\circ\text{C}$
$V_{GE(\text{th})}$	G-E threshold voltage	5.0	5.8	6.5	V	$I_C = 3200\mu\text{A}$ , $V_{CE} = V_{GE}$
$I_{CES}$	Zero gate voltage collector current	-	-	5	mA	$V_{GE} = 0\text{V}$ , $V_{CE} = 600\text{V}$
$I_{GES}$	G-E leakage current	-	-	0.4	$\mu\text{A}$	$V_{GE} = \pm 20\text{V}$
$R_{Gint}$	Internal gate resistance	-	2.0	-	$\Omega$	-
$C_{ies}$	Input capacitance	-	13	-	nF	$V_{GE} = 0\text{V}$ , $f = 1\text{MHz}$ , $V_{CE} = 25\text{V}$ , $T_{vj} = 25^\circ\text{C}$
$C_{oes}$	Output capacitance	-	0.77	-		
$C_{res}$	Reverse transfer capacitance	-	0.37	-		
$Q_g$	Total gate charge	-	1.5	-	$\mu\text{C}$	$V_{GE} = \pm 15\text{V}$
$t_{d(on)}$	Turn off delay time	-	160	-	ns	$V_{CE} = 300\text{V}$ , $I_C = 200\text{A}$ , $V_{GE} = \pm 15\text{V}$ , $R_G = 3.9\Omega$ , $T_{vj} = 150^\circ\text{C}$
$t_r$	Turn-on rise time	-	68	-		
$t_{d(off)}$	Turn-off delay time	-	520	-		
$t_f$	Turn-off fall time	-	49	-		
$E_{ON}$	Turn-on Energy loss	-	14	-	mJ	
$E_{OFF}$	Turn-off Energy loss	-	8	-		

## ■ ELECTRICAL CHARACTERISTICS OF FRD

 $T_j=25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Min	Typ	Max	Unit	Conditions
$V_F$	Diode Forward Voltage Drop	-	1.4	-	V	$T_{vj} = 25^\circ\text{C}$
		-	1.35	-		$T_{vj} = 150^\circ\text{C}$
$I_{rr}$	Peak Reverse Recovery Current	-	100	-	A	$I_F = 200\text{A}$ , $V_{CE} = 300\text{V}$ $V_{GE} = -15\text{V}$ , $T_{vj} = 150^\circ\text{C}$
$Q_{rr}$	Diode Recovery Charge	-	32	-		

## ■ THERMAL AND MECHANICAL CHARACTERISTICS

 $T_j=25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Min	Typ	Max	Unit	Condition
$R_{th(j-c)}$	Junction-to-Case (IGBT Part, Per 1/2 Module)	-	0.22	-	K/W	
$R_{th(j-c)}$	Junction-to-Case (FRD Part, Per 1/2 Module)	-	0.4	-	K/W	
$R_{th(c-f)}$	Case-to-Heat Sink (With Thermal Compound)	-	0.05	-	K/W	
Weight	Module		180		g	

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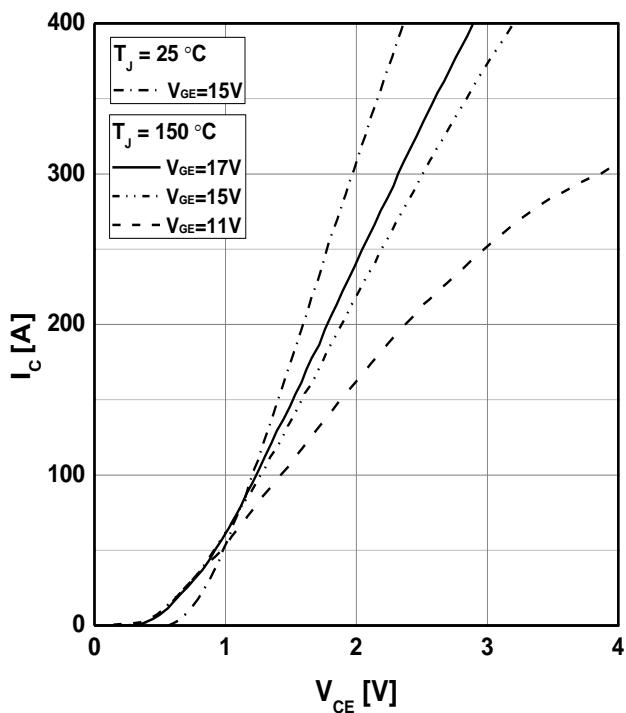
**■ PERFORMANCE CURVES (I)**

Fig1. Typical Output Characteristics

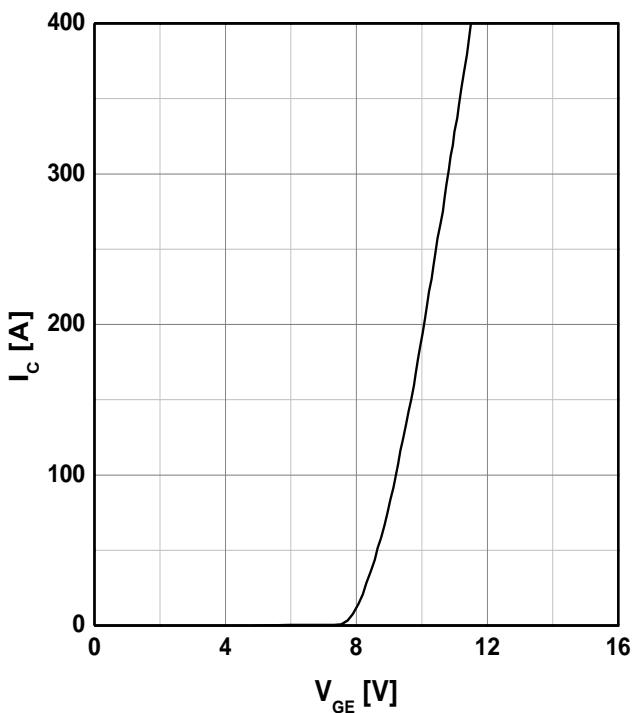
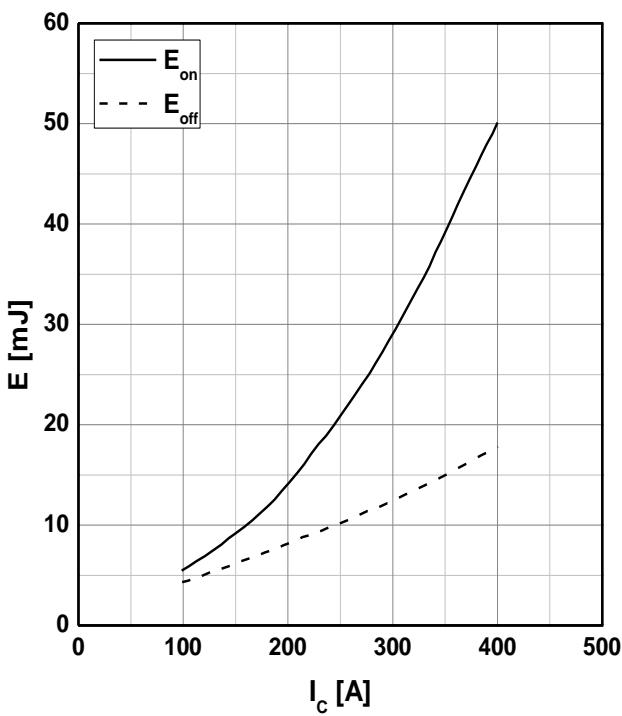
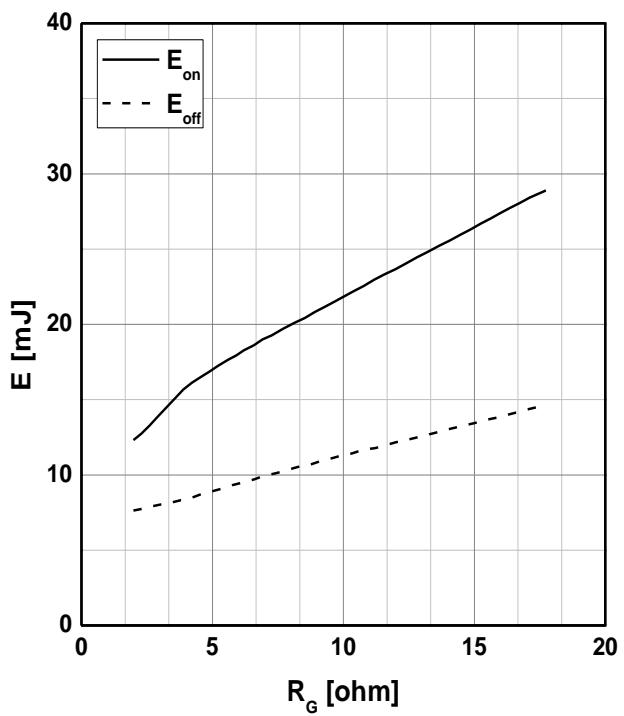


Fig2. Transfer Characteristics

Fig3. Energy Loss vs.  $I_c$ Fig4. Energy Loss vs.  $R_G$

## ■ PERFORMANCE CURVES (II)

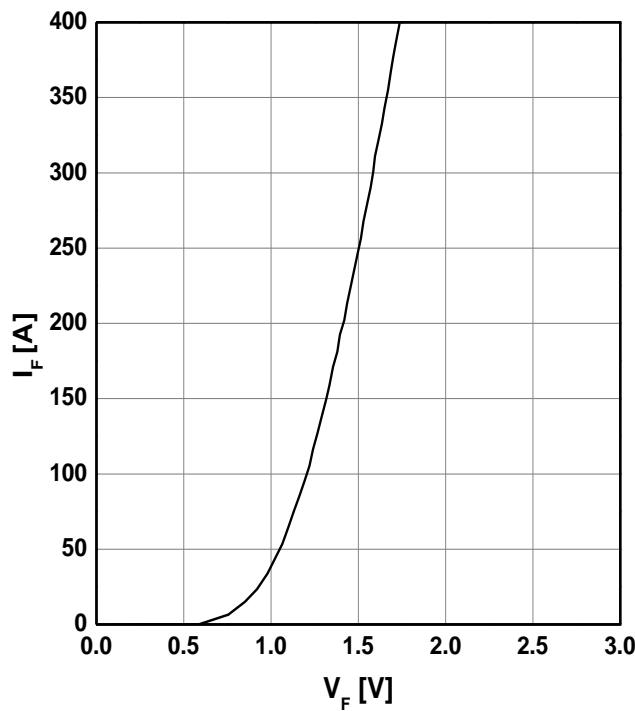


Fig5. DIODE Forward Characteristic

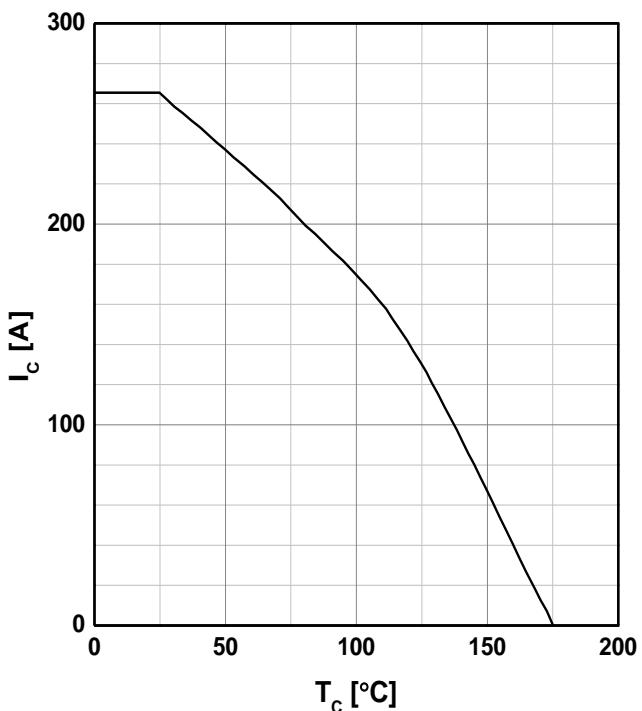
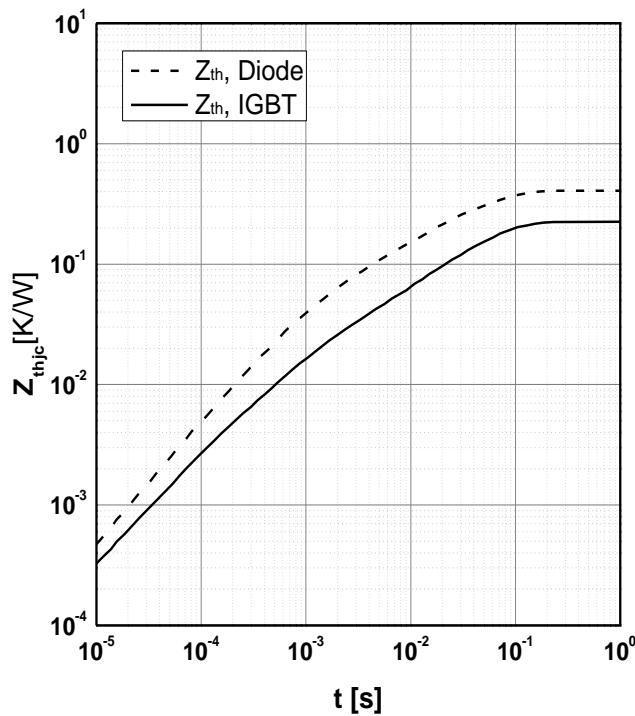
Fig6. Reverse Bios SOA ( $T_{vj} = 125$  °C)

Fig7. Transient Thermal

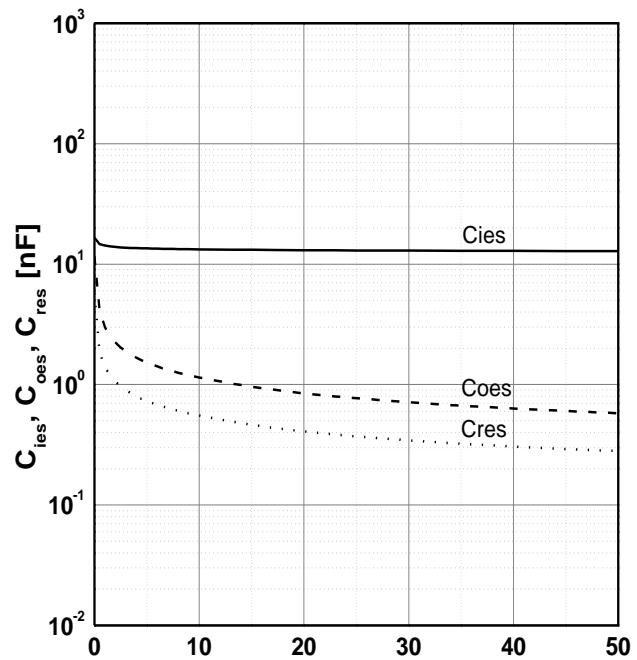


Fig8. Typ. Capacitance

## PRELIMINARY

## ■ PACKAGE OUTLINES

